

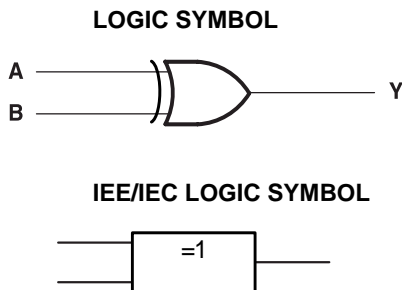
# RS4G86 Quadruple 2-Input Exclusive-OR Gate

## FEATURES

- Operating Voltage Range: 1.65V to 5.5V
- Low Power Consumption: 1µA (Max)
- Operating Temperature Range: -40°C to +125°C
- Inputs Accept Voltage to 5.5V
- High Output Drive: ±24mA at V<sub>CC</sub>=3.0V
- PACKAGES: SOIC-14(SOP14) and TSSOP-14

## APPLICATIONS

- AV Receiver
- Blu-ray Player and Home Theater
- Digital Picture Frame (DPF)
- High-Speed Data Acquisition and Generation
- Personal Navigation Device (GPS)
- Portable Media Player



## DESCRIPTION

The RS4G86 Quadruple 2-input exclusive-OR gate is designed for 1.65V to 5.5V V<sub>CC</sub> operation.

The RS4G86 device performs the Boolean function  $Y = \bar{A}B + A\bar{B}$  in positive logic. The device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The RS4G86 is available in Green SOIC-14(SOP14) and TSSOP-14 packages. It operates over an ambient temperature range of -40°C to +125°C.

### Device Information <sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
RS4G86	SOIC-14(SOP14)	8.65mm × 3.90mm
	TSSOP-14	5.00mm × 4.40mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### FUNCTION TABLE

INPUTS		OUTPUT
A	B	Y
H	H	L
L	H	H
H	L	H
L	L	L

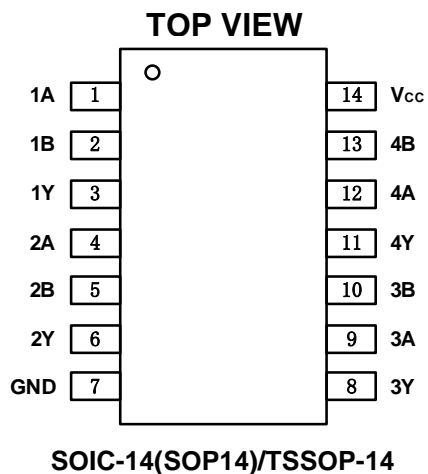
H=High Voltage Level  
L=Low Voltage Level

## Revision History

Note: Page numbers for previous revisions may differ from page numbers in the current version.

Version	Change Date	Change Item
A.1	2021/1/21	initial version completed

## PIN CONFIGURATIONS



## PIN DESCRIPTION

PIN	NAME	I/O TYPE	FUNCTION
<b>SOIC-14(SOP14)/TSSOP-14</b>			
1	1A	I	Channel 1 logic input
2	1B	I	Channel 1 logic input
3	1Y	O	Logic level output1
4	2A	I	Channel 2 logic input
5	2B	I	Channel 2 logic input
6	2Y	O	Logic level output2
7	GND	-	Ground
8	3Y	O	Logic level output3
9	3A	I	Channel 3 logic input
10	3B	I	Channel 3 logic input
11	4Y	O	Logic level output4
12	4A	I	Channel 4 logic input
13	4B	I	Channel 4 logic input
14	Vcc	-	Power Supply

## Specifications

### Absolute Maximum Ratings <sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted) <sup>(1)(2)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	6.5	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	-0.5	6.5	V
V <sub>O</sub>	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
V <sub>O</sub>	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> <0	-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> <0	-50	mA
I <sub>O</sub>	Continuous output current		±50	mA
	Continuous current through V <sub>CC</sub> or GND		±100	mA
T <sub>J</sub>	Junction temperature		150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CC</sub> is provided in the *Recommended Operating Conditions table*.

### ESD Ratings

		VALUE	UNIT	
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM)	±8000	V
		Machine model (MM)	±500	V

### Thermal Information:

THERMAL METRIC <sup>(1)</sup>		RS4G86		UNIT
		14PINS		
		SOIC-14(SOP14)	TSSOP-14	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	122.2	141.2	°C/W
R <sub>θJC(top)</sub>	Junction-to-case(top) thermal resistance	80.9	78.8	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	80.6	85.8	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	40.4	27.7	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	80.3	85.5	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case(bottom) thermal resistance	N/A	N/A	°C/W

**PACKAGE/ORDERING INFORMATION**

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING <sup>(1)</sup>	PACKAGE OPTION
RS4G86	RS4G86XP	-40°C ~+125°C	SOIC-14(SOP14)	RS4G86	Tape and Reel,4000
	RS4G86XQ	-40°C ~+125°C	TSSOP-14	RS4G86	Tape and Reel,4000

## NOTE:

- (1) There may be additional marking, which relates to the lot trace code information(data code and vendor code), the logo or the environmental category on the device.

## ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (TYP values are at  $T_A = +25^\circ\text{C}$ , unless otherwise noted.) <sup>(1)</sup>

### Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply voltage	$V_{CC}$	Operating	1.65	5.5	V
		Data retention only	1.5		
High-level input voltage	$V_{IH}$	$V_{CC}=1.65\text{V to }1.95\text{V}$	$0.65 \times V_{CC}$		V
		$V_{CC}=2.3\text{V to }2.7\text{V}$	1.7		
		$V_{CC}=3\text{V to }3.6\text{V}$	2.2		
		$V_{CC}=4.5\text{V to }5.5\text{V}$	$0.7 \times V_{CC}$		
Low-level input voltage	$V_{IL}$	$V_{CC}=1.65\text{V to }1.95\text{V}$		$0.20 \times V_{CC}$	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$		0.3	
		$V_{CC}=3\text{V to }3.6\text{V}$		0.4	
		$V_{CC}=4.5\text{V to }5.5\text{V}$		$0.15 \times V_{CC}$	
Input voltage	$V_I$		0	5.5	V
Output voltage	$V_O$		0	$V_{CC}$	V
Input transition rise or fall	$t_r, t_f$	$V_{CC}=1.8\text{V} \pm 0.15\text{V}, 2.5\text{V} \pm 0.2\text{V}$		20	ns/V
		$V_{CC}=3.3\text{V} \pm 0.3\text{V}$		10	
		$V_{CC}=5\text{V} \pm 0.5\text{V}$		5	
Operating temperature	$T_A$		-40	+125	$^\circ\text{C}$

### DC Characteristics

PARAMETER	TEST CONDITIONS	$V_{CC}$	TEMP	MIN	TYP	MAX	UNIT	
$V_{OH}$	$I_{OH} = -100\mu\text{A}$	1.65V to 5.5V	Full	$V_{CC}-0.1$			V	
	$I_{OH} = -4\text{mA}$	1.65V		1.2				
	$I_{OH} = -8\text{mA}$	2.3V		1.9				
	$I_{OH} = -16\text{mA}$	3V		2.4				
	$I_{OH} = -24\text{mA}$			2.3				
	$I_{OH} = -32\text{mA}$	4.5V		3.8				
$V_{OL}$	$I_{OL} = 100\mu\text{A}$	1.65V to 5.5V	Full			0.1	V	
	$I_{OL} = 4\text{mA}$	1.65V				0.45		
	$I_{OL} = 8\text{mA}$	2.3V				0.3		
	$I_{OL} = 16\text{mA}$	3V				0.4		
	$I_{OL} = 24\text{mA}$					0.55		
	$I_{OL} = 32\text{mA}$	4.5V				0.55		
$I_i$	A or B inputs	$V_I=5.5\text{V or GND}$	0V to 5.5V	+25 $^\circ\text{C}$		$\pm 0.1$	$\pm 1$	$\mu\text{A}$
				Full			$\pm 5$	
$I_{off}$	$V_I$ or $V_O=5.5\text{V}$	0V		+25 $^\circ\text{C}$		$\pm 0.1$	$\pm 1$	$\mu\text{A}$
				Full			$\pm 10$	
$I_{CC}$	$V_I=5.5\text{V or GND}, I_o=0$	1.65V to 5.5V		+25 $^\circ\text{C}$		0.1	1	$\mu\text{A}$
				Full			10	
$\Delta I_{CC}$	One input at $V_{CC}-0.6\text{V}$ , Other inputs at $V_{CC}$ or GND	3V to 5.5V	Full			500	$\mu\text{A}$	

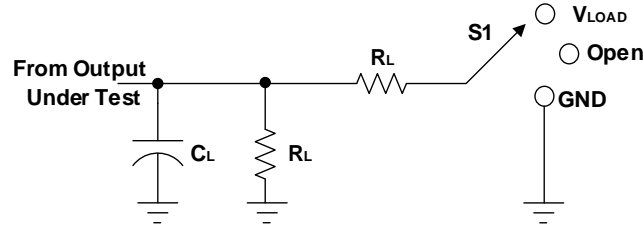
**AC Characteristics**

( $T_A = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ , typical values are at  $T_A = +25^{\circ}\text{C}$ , unless otherwise noted.) <sup>(1)</sup>

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Propagation Delay	$t_{pd}$	$V_{CC}=1.8V\pm 0.15V$	$C_L=30\text{pF}, R_L=1\text{k}\Omega$		14.2		ns
		$V_{CC}=2.5V\pm 0.2V$	$C_L=30\text{pF}, R_L=500\Omega$		11.1		
		$V_{CC}=3.3V\pm 0.3V$	$C_L=50\text{pF}, R_L=500\Omega$		6.7		
		$V_{CC}=5V\pm 0.5V$	$C_L=50\text{pF}, R_L=500\Omega$		5.3		
Input Capacitance	$C_i$	$V_{CC}=3.3V$	$V_i=V_{CC}$ or GND		4		pF
Power dissipation capacitance	$C_{pd}$	$V_{CC}=1.8V$	f=10MHz		20		pF
		$V_{CC}=2.5V$			21		
		$V_{CC}=3.3V$			22		
		$V_{CC}=5V$			25		

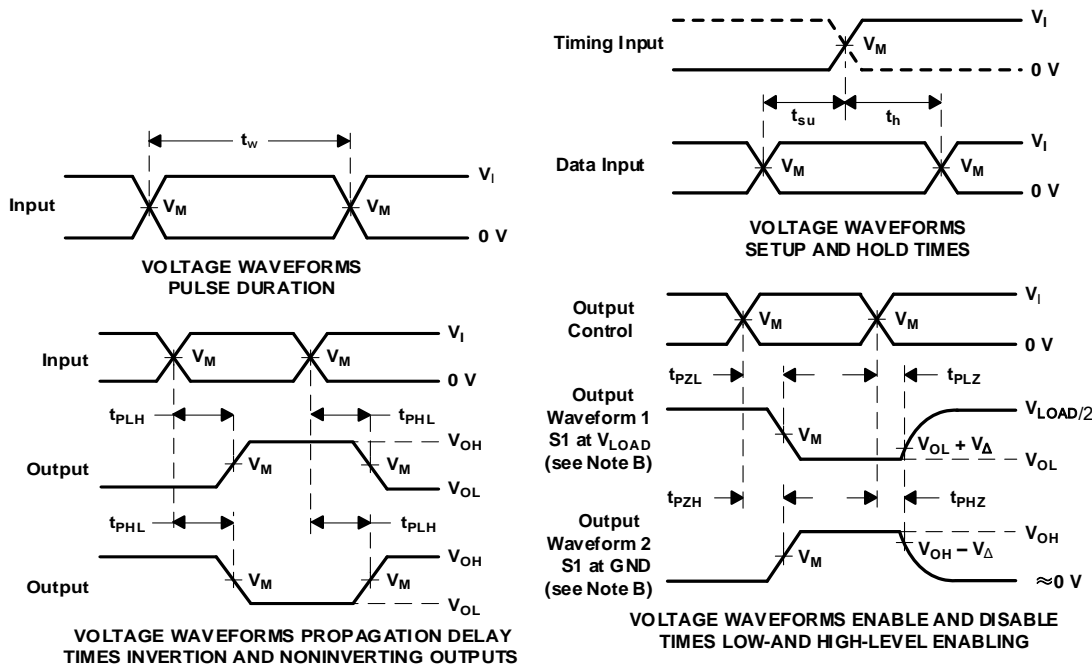
(1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.

## Parameter Measurement Information



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	INPUTS		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
$1.8V \pm 0.15V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M $\Omega$	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M $\Omega$	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	6V	15pF	1M $\Omega$	0.3V
$5V \pm 0.5V$	$V_{CC}$	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M $\Omega$	0.3V



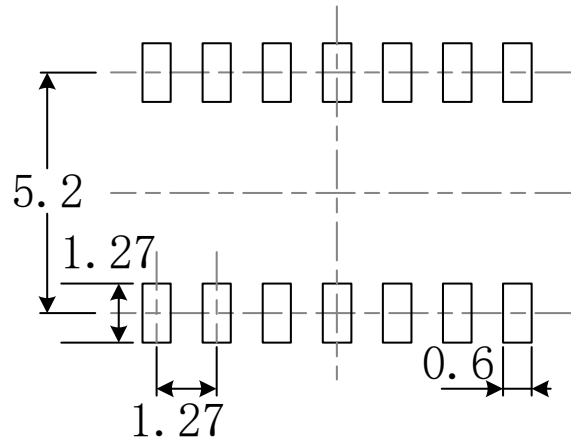
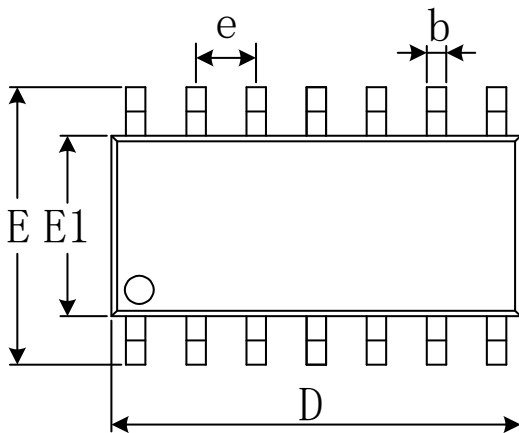
- NOTES: A.  $C_L$  includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.  
 C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ .  
 D. The outputs are measured one at a time, with one transition per measurement.  
 E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .  
 F.  $t_{ZL}$  and  $t_{ZH}$  are the same as  $t_{en}$ .  
 G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .  
 H. All parameters and waveforms are not applicable to all devices.

**Figure 1. Load Circuit and Voltage Waveforms**

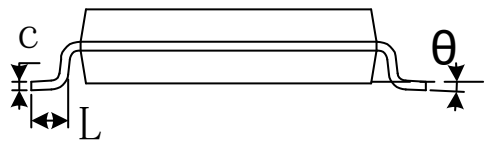
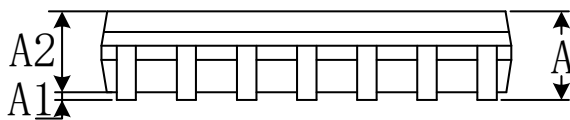


# PACKAGE OUTLINE DIMENSIONS

## SOIC-14(SOP14)

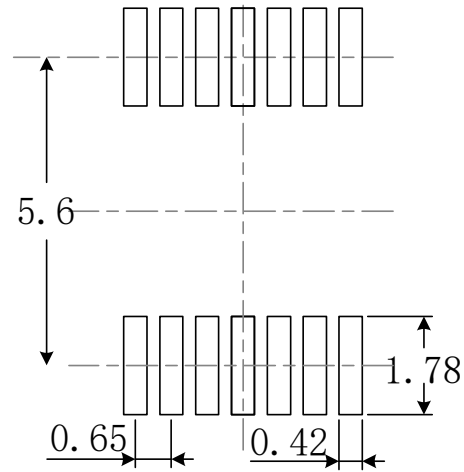
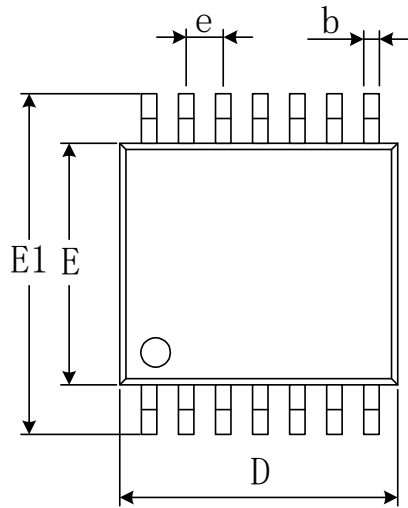


RECOMMENDED LAND PATTERN (Unit: mm)

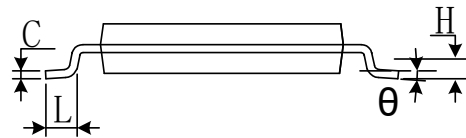
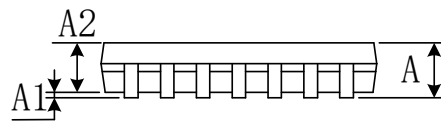


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D	8.450	8.850	0.333	0.348
e	1.270(BSC)		0.050(BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
$\theta$	0°	8°	0°	8°

# TSSOP-14



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650(BSC)		0.026(BSC)	
L	0.500	0.700	0.020	0.028
H	0.25(TYP)		0.01(TYP)	
$\theta$	1°	7°	1°	7°